BLS7G3135L-350P; BLS7G3135LS-350P LDMOS S-band radar power transistor

Rev. 4 — 1 September 2015



Product profile 1.

1.1 General description

350 W LDMOS power transistor intended for radar applications in the 3.1 GHz to 3.5 GHz range.

Table 1. **Typical performance**

Typical RF performance at $T_{case} = 25 \ ^{\circ}C$; $t_p = 300 \ \mu s$; $\delta = 10 \ ^{\circ}$; $I_{Da} = 200 \ mA$; in a class-AB production test circuit.

Test signal	f	V _{DS}	PL	Gp	η_D	t _r	t _f
	(GHz)	(V)	(W)	(dB)	(%)	(ns)	(ns)
pulsed RF	3.1	32	350	12	43	5	5
	3.3	32	350	12	43	5	5
	3.5	32	350	10	39	5	5

1.2 Features and benefits

- Easy power control
- Integrated ESD protection
- High flexibility with respect to pulse formats
- Excellent ruggedness
- High efficiency
- Excellent thermal stability
- Designed for broadband operation (3.1 GHz to 3.5 GHz)
- Internally matched for ease of use
- Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)

1.3 Applications

S-Band power amplifiers for radar applications in the 3.1 GHz to 3.5 GHz frequency range

LDMOS S-band radar power transistor

sym117

2. Pinning information

Pin	Description		Simplified outline	Graphic symbol
BLS7G3 ²	135L-350P (SOT539A)			
1	drain1			
2	drain2			
3	gate1			3
4	gate2			5
5	source	[1]		

BLS7G3135LS-350P (SOT539B)1drain12drain23gate14gate25source11 $\begin{array}{c} 1 \\ 3 \\ 4 \end{array}$ 2 $\begin{array}{c} 1 \\ 3 \\ 4 \end{array}$ 4 $\begin{array}{c} 1 \\ 3 \\ 4 \end{array}$ 5 $\begin{array}{c} 1 \\ 3 \\ 4 \end{array}$ 5 $\begin{array}{c} 1 \\ 3 \\ 4 \end{array}$ 11 $\begin{array}{c} 1 \\ 3 \\ 4 \end{array}$

[1] Connected to flange.

3. Ordering information

Table 3.Ordering information

Type number	Package					
	Name	Description	Version			
BLS73135L-350P	-	flanged balanced ceramic package; 2 mounting holes; 4 leads	SOT539A			
BLS73135LS-350P	-	earless flanged balanced ceramic package; 4 leads	SOT539B			

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Min	Max	Unit
V _{DS}	drain-source voltage	-	65	V
V _{GS}	gate-source voltage	-0.5	+11	V
T _{stg}	storage temperature	-65	+150	°C
Tj	junction temperature	<u>[1]</u> _	225	°C

[1] Continuous use at maximum temperature will affect the reliability. For details refer to the on-line MTF calculator.

LDMOS S-band radar power transistor

5. Thermal characteristics

Table 5.	Thermal characteristics			
Symbol	Parameter	Conditions	Тур	Unit
Z _{th(j-mb)}	transient thermal impedance from junction to	T_{case} = 85 °C; P _L = 350 W		
	mounting base	t_p = 300 μ s; δ = 10 %	0.1	K/W
		t_p = 100 μ s; δ = 20 %	0.09	K/W
		t_p = 100 μ s; δ = 10 %	0.07	K/W
		t_p = 200 μ s; δ = 10 %	0.09	K/W

6. Characteristics

Table 6. DC characteristics

 $T_i = 25 \ ^{\circ}C$ unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
V _{(BR)DSS}	drain-source breakdown voltage	V_{GS} = 0 V; I _D = 2.2 mA	65	-	-	V
V _{GS(th)}	gate-source threshold voltage	V _{DS} = 10 V; I _D = 220 mA	1.5	1.9	2.3	V
I _{DSS}	drain leakage current	V_{GS} = 0 V; V_{DS} = 28 V	-	-	2.8	μA
I _{DSX}	drain cut-off current	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $V_{DS} = 10 \text{ V}$	-	39	-	A
I _{GSS}	gate leakage current	V_{GS} = 11 V; V_{DS} = 0 V	-	-	280	nA
g _{fs}	forward transconductance	V _{DS} = 10 V; I _D = 11 A	-	16.2	-	S
R _{DS(on)}	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 3.75 V;$ I _D = 7.7 A	-	0.065	-	Ω

LDMOS S-band radar power transistor

Table 7. RF characteristics

Test signal: pulsed RF; $t_p = 300 \ \mu s$; $\delta = 10 \ \%$; RF performance at $V_{DS} = 32 \ V$; $I_{Dq} = 200 \ mA$; $T_{case} = 25 \ \%$; unless otherwise specified, in a class-AB production circuit.

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
At frequenc	y of 3.1 GHz					
G _p	power gain	P _L = 350 W	10.5	12	-	dB
RL _{in}	input return loss	P _L = 350 W	-	-6	-	dB
η _D	drain efficiency	P _L = 350 W	38	43	-	%
P _{droop(pulse)}	pulse droop power	P _L = 350 W	-	0.2	0.3	dB
t _r	rise time	P _L = 350 W	-	5	50	ns
t _f	fall time	P _L = 350 W	-	5	50	ns
At frequenc	y of 3.3 GHz					
G _p	power gain	P _L = 350 W	10.5	12	-	dB
RL _{in}	input return loss	P _L = 350 W	-	-6	-	dB
η_D	drain efficiency	P _L = 350 W	38	43	-	%
P _{droop(pulse)}	pulse droop power	P _L = 350 W	-	0.2	0.3	dB
t _r	rise time	P _L = 350 W	-	5	50	ns
t _f	fall time	P _L = 350 W	-	5	50	ns
At frequenc	y of 3.5 GHz					
G _p	power gain	P _L = 320 W	8.5	10	-	dB
RL _{in}	input return loss	P _L = 320 W	-	-9	-	dB
η _D	drain efficiency	P _L = 320 W	35	39	-	%
P _{droop(pulse)}	pulse droop power	P _L = 320 W	-	0.2	0.3	dB
t _r	rise time	P _L = 320 W	-	5	50	ns
t _f	fall time	P _L = 320 W	-	5	50	ns

7. Application information

7.1 Ruggedness in class-AB operation

The BLS7G3135L-350P and the BLS7G3135LS-350P are capable of withstanding a load mismatch corresponding to VSWR = 10 : 1 through all phases under the following conditions: V_{DS} = 32 V; I_{Dg} = 200 mA; P_L = 350 W; t_p = 300 μ s; δ = 10 %

LDMOS S-band radar power transistor

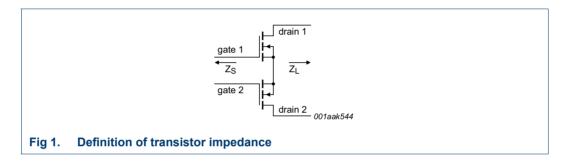
7.2 Impedance information

Table 8. Typical impedance

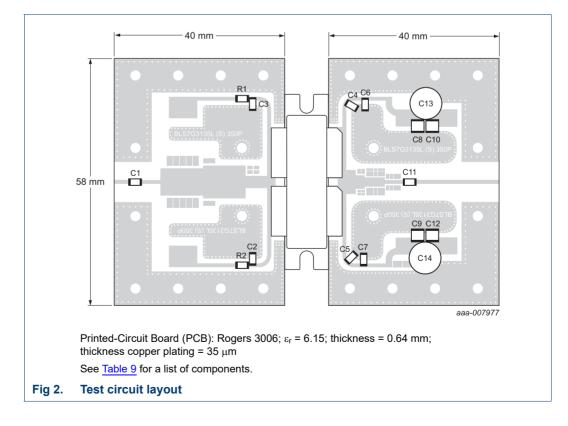
Measured load-pull data. Typical values unless otherwise specified.

f	Z _S [1]	ZL ^[1]
(GHz)	(Ω)	(Ω)
3.1	1.8 – 7.2j	3.6 – 6.3j
3.2	1.6 – 7.1j	4.4 – 6.7j
3.3	2.2 – 8.2j	4.8 – 5.8j
3.4	3.1 – 9.7j	5.7 – 6.2j
3.5	3.6 – 11.6j	6.5 – 4.6j

[1] Impedances are taken at a single half of the push-pull transistor.



7.3 Test circuit information

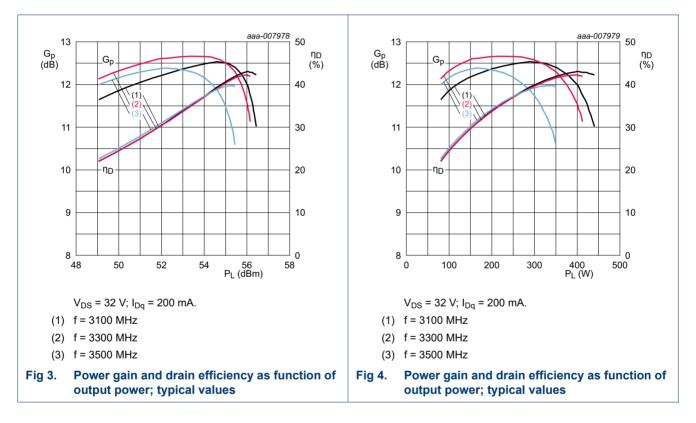


LDMOS S-band radar power transistor

Table 9.List of componentsFor test circuit see Figure 2.

Component	Description	Value	Remarks		
C1, C2, C3	multilayer ceramic chip capacitor	8.2 pF	ATC100A		
C4, C5, C11	multilayer ceramic chip capacitor	15 pF	ATC800B		
C6, C7	multilayer ceramic chip capacitor	100 pF	ATC800A		
C8, C9	multilayer ceramic chip capacitor	1 μF, 50 V	TDK		
C10, C12	multilayer ceramic chip capacitor	10 μF, 50 V	TDK		
C13, C14	electrolytic capacitor	220 μF, 63 V			
R1, R2	SMD resistor	10 Ω			

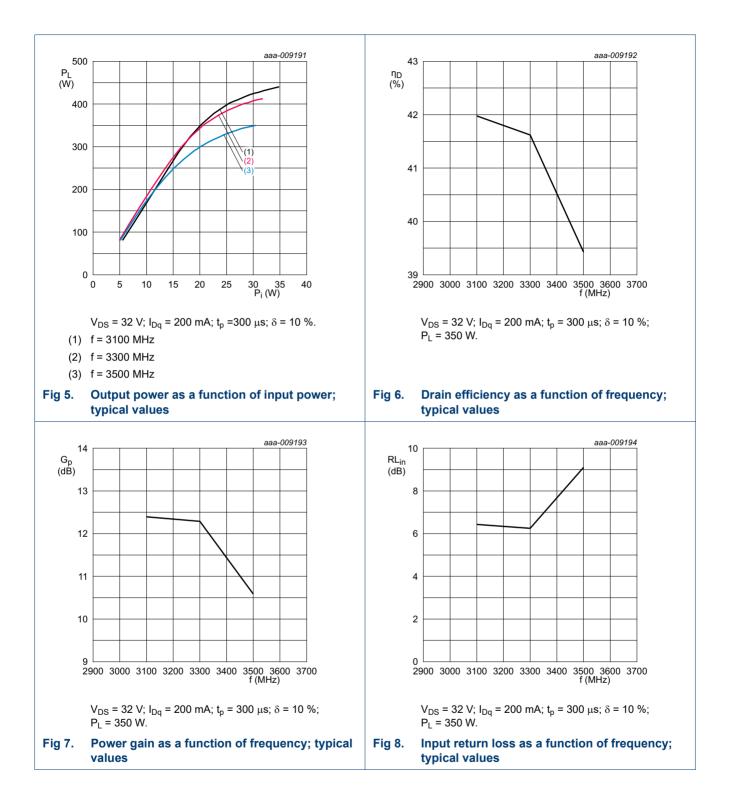
7.4 Graphical data



AMPLEON

BLS7G3135L(S)-350P

LDMOS S-band radar power transistor



LDMOS S-band radar power transistor

8. Package outline

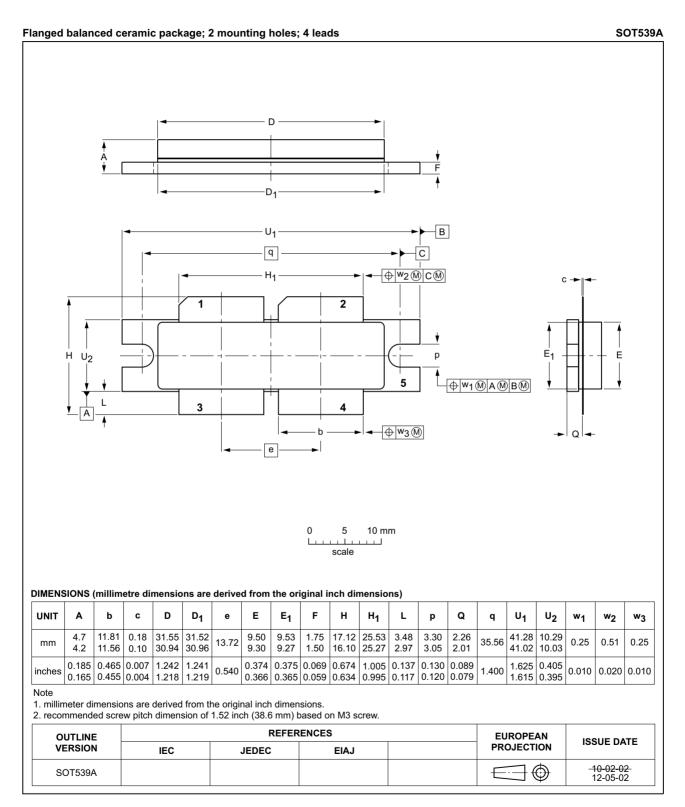


Fig 9. Package outline SOT539A

LDMOS S-band radar power transistor

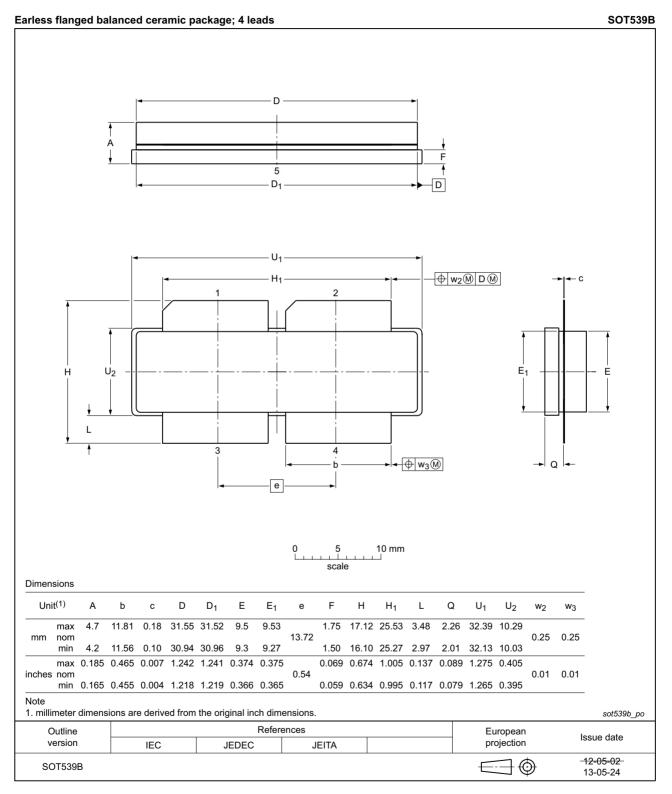


Fig 10. Package outline SOT539B

BLS7G3135L-350P_7G3135LS-350P#4

LDMOS S-band radar power transistor

9. Handling information

CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the ANSI/ESD S20.20, IEC/ST 61340-5, JESD625-A or equivalent standards.

10. Abbreviations

Table 10. Abbreviations				
Acronym	Description			
ESD	ElectroStatic Discharge			
LDMOS	Laterally Diffused Metal Oxide Semiconductor			
S-Band	Short wave band			
SMD	Surface Mounted Device			
VSWR	Voltage Standing-Wave Ratio			

11. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BLS73135L-350P_7G3135LS-350P#4	20150901	Product data sheet		BLS73135L-350P_7G31 35LS-350P v.3
Modifications:		t of this document has l idelines of Ampleon.	been redesigned t	o comply with the new
	 Legal texts 	have been adapted to	the new company	/ name where appropriate.
BLS73135L-350P_7G3135LS-350P v.3	20131029	Product data sheet	-	BLS73135L-350P_ 7G3135LS-350P v.2
BLS73135L-350P_7G3135LS-350P v.2	20130801	Objective data sheet	-	BLS73135L-350P_ 7G3135LS-350P v.1
BLS73135L-350P_7G3135LS-350P v.1	20121012	Objective data sheet	-	-

12. Legal information

12.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition	
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.	
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.	
Product [short] data sheet	Production	This document contains the product specification.	

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.ampleon.com.

12.2 Definitions

Draft — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. Ampleon does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

Short data sheet — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local Ampleon sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

Product specification — The information and data provided in a Product data sheet shall define the specification of the product as agreed between Ampleon and its customer, unless Ampleon and customer have explicitly agreed otherwise in writing. In no event however, shall an agreement be valid in which the Ampleon product is deemed to offer functions and qualities beyond those described in the Product data sheet.

12.3 Disclaimers

Limited warranty and liability — Information in this document is believed to be accurate and reliable. However, Ampleon does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information. Ampleon takes no responsibility for the content in this document if provided by an information source outside of Ampleon.

In no event shall Ampleon be liable for any indirect, incidental, punitive, special or consequential damages (including - without limitation - lost profits, lost savings, business interruption, costs related to the removal or replacement of any products or rework charges) whether or not such damages are based on tort (including negligence), warranty, breach of contract or any other legal theory.

Notwithstanding any damages that customer might incur for any reason whatsoever, Ampleon' aggregate and cumulative liability towards customer for the products described herein shall be limited in accordance with the *Terms and conditions of commercial sale* of Ampleon.

Right to make changes — Ampleon reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

Suitability for use — Ampleon products are not designed, authorized or warranted to be suitable for use in life support, life-critical or safety-critical systems or equipment, nor in applications where failure or malfunction of an Ampleon product can reasonably be expected to result in personal injury, death or severe property or environmental damage. Ampleon and its suppliers accept no liability for inclusion and/or use of Ampleon products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

Applications — Applications that are described herein for any of these products are for illustrative purposes only. Ampleon makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Customers are responsible for the design and operation of their applications and products using Ampleon products, and Ampleon accepts no liability for any assistance with applications or customer product design. It is customer's sole responsibility to determine whether the Ampleon product is suitable and fit for the customer's applications and products planned, as well as for the planned application and use of customer's third party customer(s). Customers should provide appropriate design and operating safeguards to minimize the risks associated with their applications and products.

Ampleon does not accept any liability related to any default, damage, costs or problem which is based on any weakness or default in the customer's applications or products, or the application or use by customer's third party customer(s). Customer is responsible for doing all necessary testing for the customer's applications and products using Ampleon products in order to avoid a default of the applications and the products or of the application or use by customer's third party customer's third party customer's third party customer's application and the products or of the application or use by customer's third party customer(s). Ampleon does not accept any liability in this respect.

Limiting values — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) will cause permanent damage to the device. Limiting values are stress ratings only and (proper) operation of the device at these or any other conditions above those given in the Recommended operating conditions section (if present) or the Characteristics sections of this document is not warranted. Constant or repeated exposure to limiting values will permanently and irreversibly affect the quality and reliability of the device.

Terms and conditions of commercial sale — Ampleon products are sold subject to the general terms and conditions of commercial sale, as published at http://www.ampleon.com/terms, unless otherwise agreed in a valid written individual agreement. In case an individual agreement is concluded only the terms and conditions of the respective agreement shall apply. Ampleon hereby expressly objects to applying the customer's general terms and conditions with regard to the purchase of Ampleon products by customer.

No offer to sell or license — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

Export control — This document as well as the item(s) described herein may be subject to export control regulations. Export might require a prior authorization from competent authorities.

BLS7G3135L-350P_7G3135LS-350P#4

LDMOS S-band radar power transistor

Non-automotive qualified products — Unless this data sheet expressly states that this specific Ampleon product is automotive qualified, the product is not suitable for automotive use. It is neither qualified nor tested in accordance with automotive testing or application requirements. Ampleon accepts no liability for inclusion and/or use of non-automotive qualified products in automotive equipment or applications.

In the event that customer uses the product for design-in and use in automotive applications to automotive specifications and standards, customer (a) shall use the product without Ampleon' warranty of the product for such automotive applications, use and specifications, and (b) whenever customer uses the product for automotive applications beyond Ampleon' specifications such use shall be solely at customer's own risk, and (c) customer fully indemnifies Ampleon for any liability, damages or failed product claims resulting from customer design and use of the product for automotive applications beyond Ampleon' standard warranty and Ampleon' product specifications.

Translations — A non-English (translated) version of a document is for reference only. The English version shall prevail in case of any discrepancy between the translated and English versions.

13. Contact information

For more information, please visit: http://www.ampleon.com

12.4 Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

Any reference or use of any 'NXP' trademark in this document or in or on the surface of Ampleon products does not result in any claim, liability or entitlement vis-à-vis the owner of this trademark. Ampleon is no longer part of the NXP group of companies and any reference to or use of the 'NXP' trademarks will be replaced by reference to or use of Ampleon's own Any reference or use of any 'NXP' trademark in this document or in or on the surface of Ampleon products does not result in any claim, liability or entitlement vis-à-vis the owner of this trademark. Ampleon is no longer part of the NXP group of companies and any reference to or use of the 'NXP' trademark will be replaced by reference to or use of the 'NXP' trademark in this document or in or on the surface of Ampleon products does not result in any claim, liability or entitlement vis-à-vis the owner of this trademark. Ampleon is no longer part of the NXP group of companies and any reference to or use of the 'NXP' trademarks will be replaced by reference to or use of Ampleon's own trademarks.

For sales office addresses, please visit: http://www.ampleon.com/sales

LDMOS S-band radar power transistor

14. Contents

1	Product profile	1
1.1	General description	1
1.2	Features and benefits	1
1.3	Applications	1
2	Pinning information	2
3	Ordering information	2
4	Limiting values	2
5	Thermal characteristics	3
6	Characteristics	3
7	Application information.	4
7.1	Ruggedness in class-AB operation	
7.2	Impedance information	5
7.3	Test circuit information	5
7.4	Graphical data	6
8	Package outline	8
9	Handling information	10
10	Abbreviations	10
11	Revision history	10
12	Legal information	11
12.1	Data sheet status	11
12.2	Definitions	11
12.3	Disclaimers	11
12.4	Trademarks	12
13	Contact information	12
14	Contents	13

Please be aware that important notices concerning this document and the product(s) described herein, have been included in section 'Legal information'.

© Ampleon The Netherlands B.V. 2015.

All rights reserved.

For more information, please visit: http://www.ampleon.com For sales office addresses, please visit: http://www.ampleon.com/sales Date of release: 1 September 2015

Document identifier: BLS7G3135L-350P_7G3135LS-350P#4